from the resistance of the bridging nitrogen atoms to large deformations from a tetrahedral configuration. For compounds which contain an N-N bond, the dihedral angle defined above may provide a means of estimating the limits of deformation of the bridging system. Further structural studies on related compounds are being carried out to determine whether this approach is one of general predictive utility.

Acknowledgments.-The use of the Picker diffractometer at Xorthwestern University for collection of the intensity data was made possible through the generous hospitality of Professor J. A. Ibers. This work was supported by the National Science Foundation. Computation was supported in part by an NSF institutional grant to the University of California, Irvine, Calif,

CONTRIBUTION FROM THE DEPARTMENT OF CHEMISTRY. UNIVERSITY OF CANTERBURY, CHRISTCHURCH, NEW ZEALAND

The Crystal and Molecular Structure of Trifluorosilyltetracarbonylcobalt

BY K. EMERSON, PETER R. IRELAND, AND WARD T. ROBIXSON

Received February 24, 1969

The crystal and molecular structure of trifluorosilyltetracarbonyl cobalt, $Co(SiF_3)(CO)_4$, has been determined from threedimensional X-ray photographic data. The structure has been solved by symbolic addition and refined by least-squares procedures. The R factor for 375 intensities above background is 7.7%. The material crystallizes in space group Cmca of the orthorhombic system with eight molecules in a cell of dimensions $a = 8.224$ (4), $b = 11.418$ (10), and $c = 18.591$ (7) \AA . The Co-Si distance is very slightly shorter than that of the chloro derivative, but there are no other significant differences between the structures of the two molecules.

Introduction

In recent years there has been widespread interest in complexes of nonmetallic second-row donor elements with transition metals and, in particular, the role of $(d \rightarrow d)$ π bonding in stabilizing such complexes.¹⁻³ Few comparative data bearing on this question have been available. Recently Robinson and Ibers' determined the structure of $Cl₃SiCo(CO)₄$ by X-ray diffraction; the structure of $H_3SiCo(CO)_4$ has been studied by electron diffraction methods.² This paper reports the X-ray determination of the structure of a third member of this series, $(F_3Si)Co(CO)_4$. Earlier spectral work indicated that all three molecules had the same basic trigonal-bipyramidal structure, and hence it seemed likely that a comparison of bond lengths in the three compounds would be very useful in assessing the importance of $(d \rightarrow d)$ π bonding.

Experimental Section

Preparation of Crystals.--A sample of $Co(SiF₃)(CO)₄$, prepared by procedures first outlined by Chalk and Harrod,⁴ was kindly supplied by Dr. A. P. Hagen. Crystals were grown by subliming the sample from a break-seal tube into a glass capillary through which the vapor was drawn by a vacuum pump; the capillary was designed so that it could be immersed in liquid nitrogen and easily sealed and removed.

Computations.-Calculations were carried out on an IBM 360/44 computer with 16 K words of core storage and twin **2315** disk drives. The programs used have been footnoted in the text.

Determination **of** Space **Group** and Unit Cell Dimensions.- The melting point of the compound is 18°, and therefore capil-

laries containing the crystals were stored, handled, and photographed in a refrigerated room at temperatures between 0 and 6". Several different pale yellow transparent crystals were mounted and examined. Only one crystal form was found. Precession and Weissenberg photographs in several different orientations showed that the diffraction symmetry was mnim with extinctions $h + k$ odd for *hkl, l* odd for *hOl,* and *h* odd for *hkO.* These absences are consistent with space group Cmca or (with a permutation of axes) Aba2. After the complete set of structure factors had been collected and scaled *(vide infra),* normalized structure factors⁶ were calculated using the program $SIM.$ ⁶ The distribution of normalized structure factors was compared with the theoretical distributions for centric and acentric structures;⁷ the observed distribution was very close to the theoretical centric distribution. The space group Cmca was therefore chosen for refinement.

Data for unit cell determination were taken from a crystal mounted with the [110] axis parallel to the goniometer axis. Precession photographs of the *hk0* and *hhl* zones were taken with Co K_{α} radiation. All distances greater than 9.0 cm between equivalent spots were measured using a cathetometer which could be read to 0.002 mm. These distances together with the reflection indices were used as input to program CELGLS which uses an iterative least-squares procedure to refine the cell parameters. These were $a = 8.224 (4)$, $b = 11.418 (10)$, and $c =$ 18.591 (7) **A.**

Throughout this paper, numbers in parentheses are estimated standard deviations in the least significant digits and are usually derived from the inverse matrix in nonlinear least-squares calculations.

Film shrinkage corrections were not made because the photographs had been collected at one temperature and developed at another. The spots were not especially sharp and the magnitude

⁽¹⁾ W. T. Robinson and J. A. Ibers, *Imvg. Chem.,* **6,** 1208 (1967).

⁽²⁾ A. G. Robiette, G. M. Sheldinck, R. N. F. Simpson, B. J. Aylett,

and J, A. Campbell, *J. Organometal. Chem.* (Amsterdam), **14,** 279 (1968). **(3) A.** P. Hagen and **A.** G. McDiarmid, *Irzorg. Chem.,* **6,** 686 (1967).

⁽⁴⁾ A. J. Chalk and J. F. Harrod, *J. Am. Chem. Soc.,* **87, 1133** (1965).

⁽⁵⁾ H. Hauptmann and J. Karle, "Solution of the Phase Problem. I. The Centrosymmetric Crystal," American Crystallographic Association Monograph No. 3, Pittsburgh, Pa., 1953.

⁽⁶⁾ **SHKORM** is a program derived from **NRC-4** (S. **R.** Hall and F. R. Ahmed) to calculate normalized structure factors.

⁽⁷⁾ I. L. Karle, K. Britts, and P. Gum, *Acta Cyyst.,* **17,** 496 (1964).

of shrinkage errors was judged to be comparable to the measuring errors.

The density of the crystal was not determined experimentally because of its extreme sensitivity to moist air. Eight molecules per unit cell give a calculated density of **1.95** g/cm3, reasonably close to the value of 1.89 g/cm³ reported for $Cl_3SiCo(CO)_4$.¹ Thus in this case m crystallographic symmetry must be imposed on the molecule and all atoms except one carbon, one oxygen, and one fluorine must occupy special positions f in the designated space group.

Determination of the Structure.---Intensity data were collected from a second crystal, also mounted about the **[110]** axis. In this orientation the apparent symmetry is monoclinic and by collecting the full monoclinic data set one can obtain two readings of each intensity, each one from a different layer. This provided an unusually large amount of data for determining layer-to-layer scaling factors. Five layers of integrated data were collected using $Co K_{\alpha}$ radiation and the Weissenberg equiinclination technique. Integration was carried out both horizontally and vertically with a Nonius Weissenberg camera to give an approximately square spot. These data were indexed in the monoclinic system, and the plateaus of all integrated spots were measured using a single-beam photometer and a galvanometer calibrated to read intensities directly. Readings were corrected for film background in the vicinity of the spot. After the raw intensities had been corrected for Lorentz and polarization effects, the indices were transformed to the orthorhombic cell, and layer-to-layer scale factors were determined using a linear least-squares procedure described by Rae.8 The scaled reflections from different layers of data showed consistently good agreement, and the data were therefore placed on the same relative scale for the remainder of the determination, with only a single scale factor refined.

All correlation ratios were equally weighted in the above procedure. Of the 900 reflections in the region $0 \leq (\sin \theta)/\lambda \leq 0.5$, **375** were observed.

At the end of the data collection the capillary mounting of the crystal was examined with the intent of measuring the crystal dimensions to correct for absorption. However there was no crystal visible in the capillary. Apparently the X-radiation had slowly vaporized it in the course of the data collection. Close examination of the data revealed some evidence that this had been occurring. In the last layer of data collected the integrated spots displayed an odd banded appearance. Correlations between reflections taken early in the data collection and those taken late suggested that the size of the crystal was decreasing. The original size of the crystal was estimated to be 0.2 mm \times 0.1 mm X **0.05** mm with the largest dimension being in the direction of the rotation axis. The variation in absorption correction which a crystal of this size could show is of the order of 25% , but this would vary from layer to layer as the crystal diminished in size and also from spot to spot as the shape of the crystal changed during evaporation. To make any absorption correction under these circumstances would have involved much guesswork and very little proper measurement. Moreover, the procedure by which the layers were correlated involved taking averages of correlation factors between early data and late data, and this would tend to reduce the absorption error somewhat. Corrections for absorption and extinction were therefore not made at any stage of the refinement.

The fully correlated data set was then converted to a set of normalized structure factors⁵ (hereafter called *E*'s). The 147 largest *E's* were chosen for sign determination by the symbolic addition procedure.⁹ A self-consistent set of signs was obtained with one symbolic sign undetermined. The two possible *E* maps were plotted, and one clearly revealed the entire molecule.1° The parameters derived from this map were run through five

5社557223日982──※ おおひはりばらおはょっぽ **SALC** $\frac{1}{\sigma}$ $\frac{1}{\sigma}$ a
a bushenneanni 1000000000 **Sec** $\frac{1}{2}$ J. **NHNM4BNNSHB3** $\frac{1}{2}$ *ognannvære* mmmmnnann. ★ あれゅろちおい 炒りったんけれのみおおとけ 221 : ESSISIE **GALC** $\frac{1}{2}$ nes. **Bunner** neseggganshmo-mneuse L. 525 m m c m c m -1 -------- $\overline{}$ \mathbf{r} れはけのおは 「」 けびおいけあれるよりちゅうのでっちゅうりょうてきのほうる **JALG** GBS aniai もれちはもれまりも3もり7ら785B9しち985もも?ち まえるゅうもでゅうにまほねだわまでううです今辺珍まですも L. **ADOOA** $\ddot{}$ $\frac{6}{2}$ CALC ★ のけょものちといいけはにはいけっぽっぱらもおみ74のとう1も140 OB₅ ~ 2 「して、のも羽みにしけられなけれけにしい。ちはみ?おちはみにおれみ!」 CALCULATED AND OBSERVED STRUCTURE FACTORS FOR F₃SiCo(CO)4 $\overline{}$ じゅも8秒込み込取っまでちりには認証わけしまですうも?89辺はけ σ or $\ddot{}$ O JOODOJOJNNNNNNNNNNNN4444444444444 CALC っしょ こうじょう にんちう ちろうおおりちゅう としあいとにけっいはいにほう CES 112100016211122840148005412111211121112111212 \overline{a} 56787はおほおわけぇぇぅ5678 はははれおわまえるって幻は迫防すり670 × きききききききききょう ちろうちらうちらうちょうしょうしきききょうきょう 8.4. しいいいにいいりゅうほうかい * Struytにいいだいはいいいしいしい CALC **ΘB PANDOQQQAPAPQPQQ** 12. 狂畅扬起转转到在村村边边身上的时间 ω nas-kreisserese までゅうゆきのには反映的時はできる ;
♦ ==================== $\tilde{\mathbf{x}}$ eeewwwww@ddddie $\begin{array}{l} \mathfrak{d} \quad \mathfrak{d$ CALL oas も、も、213821100人の「40」たんおもおりみったっとうか!うまうしんだしでも? こうきついちんどわいかんの れったんおおおお ちょうどうちょうようしゃり J. ます50789時は記録123450789には記録や打つ123456789回記 $\ddot{}$ ※2位のあえじゅじ? 6.5.5.5.3.5.1.9.5.5丁 CALC # Gadagaskukse おびったければはほっちほほんしひりはにはほっ $C05$ **Essagerant**s そうょうもての約は返却まで356で89には起 J. じょうちにははじょう -------------------- \ddagger 0000000000000 CALC さままでまで今ままあさみ目のははほっておほぼはみねんもずせんまをはちっぽはけてももまえるでするみんちのははほっておほぼみんちゃんすせんまではちっぽはけ ABLAUNARDYAAHRABB®BAAARAARAAHARNAPDAR C6S はは私追追1234567890Ⅱはおあけね1234567890Ⅱはおらめ退1 J. **ALC** 1.237482の1124124342321791119917 $\frac{1}{2}$ serves a de **OUS** 话到相与为好好好让我认识了 礼拜之为为了 ?让扬に记者 **GESSISS** けしまて348902344012345678923 \overline{a} $-nmnonen$ CALC 2月20日のおもにのは羽っけ近びけりにじいいかばちりのはもちいけて、はあぁぁ $\tilde{\mathbf{s}}$ いまでなちら目にはいけばのみみはおねはほけの時ののほれちなけれるにありて 408 ははれねほよえきゅうもす89 ははばけっまできゅう6789 はにおばん

Тавья І

⁽⁸⁾ A. D. **Rae,** *Acta Cvyst.,* **19, 683 (1965).**

⁽⁹⁾ **Symbolic addition was carried out using SAP, a program derived from NRC-4** (S. **R. Hall and F. R. Ahmed).**

⁽¹⁰⁾ All Fourier summations were carried out **using an adapted version of A. Zalkin's FORDAP.**

TABLE **I1** FINAL POSITIONAL AND THERMAL PARAMETERS FOR $F_3SiCo(CO)_4$

Atom	х	ν		β_{11}^a	β_{22}	β 33	β_{12}	β_{15}	β_{23}
Co.	0.0	$0.1662(2)^{b}$	0.1308(1)	0.0151(4)	0.0064(3)	0.0031(1)	0.0	0.0	0.0004(1)
Si	0.0	$-0.0281(4)$	0.1410(2)	0.0209(9)	0.0074(4)	0.0035(2)	0.0	0.0	0.0006(2)
F(M)	0.0	$-0.0932(9)$	0.0708(6)	0.1050(77)	0.0084(11)	0.0060(5)	0.0	0.0	$-0.0013(6)$
F(G)	0.1454(12)	$-0.0779(7)$	0.1820(6)	0.0347(22)	0.0123(9)	0.0132(5)	0.0009(11)	$-0.0092(10)$	0.0038(6)
C(M)	0.0	0.1656(15)	0.2272(10)	0.0387(55)	0.0092(18)	0.0034(7)	0.0	0.0	$-0.0005(8)$
O(M)	0.0	0.1639(12)	0.2871(7)	0.0728(68)	0.0141(16)	0.0034(5)	0.0	0.0	$-0.0005(7)$
C(G)	0.1850(16)	0.1482(9)	0.0820(6)	0.0177(20)	0.0073(12)	0.0047(4)	$-0.0011(14)$	0.0000(8)	0.0018(5)
O(G)	0.3022(12)	0.1375(8)	0.0512(5)	0.0200(15)	0.0153(12)	0.0070(4)	$-0.0007(12)$	0.0021(7)	0.0027(5)
C(A)	0.0	0.3237(18)	0.1253(11)	0.0296(47)	0.0078(22)	0.0063(8)	0.0	0.0	$-0.0010(10)$
O(A)	0.0	0.4222(12)	0.1184(8)	0.0342(37)	0.0048(13)	0.0094(8)	0.0	0.0	0.0010(7)

a The form of the anisotropic ellipsoid is $\exp - [(\beta_{11}h^2 + \beta_{22}k^2 + \beta_{33}l^2 + 2\beta_{12}hk + 2\beta_{13}hl + 2\beta_{23}kl)]$. ^b Figures in parentheses are standard deviations computed from the inverse matrix; no deviations are given for symmetry-determined parameters.

^{*a*} Some of these are significantly lengthened by thermal motion. See text. $\frac{b}{c}$ The shortest intermolecular distances of the type specified.

cycles of full-matrix least-squares refinement 11 with all reflections equally weighted. The conventional *R* factor $(R_1 = \sum \Delta / \sum |F_0|)$ where $\Delta = ||F_0| - |F_0||$ dropped from 32.4 to 14.8% while the weighted *R* factor $(R_2 = \Sigma w \Delta^2 / \Sigma w F_0^2)$ dropped from 34.3 to 15.87,.

Least-squares refinement of the structure was then carried out along conventional lines. A weighting scheme of the form

$$
\sqrt{w} = (A + BF_0 + CF_0^2 + DF_0^3)^{-1}
$$

was calculated subject to the condition that **ZwA2** be approximately independent of $|F_{0}|$ and $(\sin \theta)/\lambda$. The constants *A*, *B,* C, and D required alterations several times during the refinement. Anisotropic temperature factors were applied to all atoms at an R_1 value of 13.8%. Least-squares refinement converged at R_1 and R_2 values of 7.7 and 8.9%, respectively. In the final cycle of refinement the values of the constants *A, B,* C, and D in the weighting expression were, respectively, 260.0, -9.20 , 0.200, and 0.0100. Three reflections, (004), (040), and (041), are obviously suffering from extinction, but for reasons discussed earlier no such correction was made. The electron density of the highest ten peaks in the final difference Fourier ranged from 0.5 to 0.25 e^{-}/\mathring{A}^{3} . These were considered acceptably low values in view of the lack of corrections for absorption and estinction. The final structure factor listing is given in Table I and the atom position and thermal parameters are given in Table 11.

Discussion of the Structure

Selected bonded and nonbonded distances are given in Table 111, and selected angles are given in Table IV.I2 The crystal consists of discrete molecules, the shortest cobalt-cobalt distance being 6.16 **if.** All intermolecular contacts are larger than the sums of the appropriate van der Waals radii. A perspective drawing of the molecule is shown in Figure 1.13 To simplify the figures, subscript letters have been used i nstead of the parenthetic letters in the text.

The rms displacements along the principal axes of the thermal ellipsoids are given in Table V. The aniso-

⁽¹¹⁾ Full-matrix least-squares refinements were carried out using **CUCILS,** a composite program containing elements of ORFLS (W. R. Busing, K. 0. (13) Figures mere drawn using CORTEP, adapted from ORTEP *(C.* K. John-Martin, and H. A. Levy), NULS4 (J. A. Ibers), and UCILS (R. J. Doedens).

_~ (12) Distances and angles were calculated using CORFFE, a program

derived from ORFFE-I1 (W. R. Busing, K. 0. Martin, and H. **A.** Levy).

Figure 1.-General view of the $F_3SiCo(CO)_4$ molecule.

tropic motions are large only for the fluorine and oxygen atoms. Orientations of the thermal ellipsoids can be seen in Figures 1 and 2, and all seem physically reasonable.

A detailed comparison of the bonded distances and angles with those determined by Robinson and Ibers' for $Cl_3SiCo(CO)_4$ raises several interesting points. The Cl-Si distance of 2.035 (3) *k* in the chloro compound is normal, while the F-Si distance of 1.51 (1) \AA reported here is significantly shorter than previously reported F-Si distances,^{$14-18$} which range from 1.55 to 1.59 Å. **A** number of corresponding distances for the two compounds have been listed in Table VI. In this table a

TABLE VI

A COMPARISON OF SOME BOND DISTANCES **(A)** IN $Cl₈SiCo(CO)₄$ AND $F₈SiCo(CO)₄^a$

a A parenthetic E indicates an average distance for the equatorial groups; a parenthetic **A** indicates an axial distance.

parenthetic E indicates an equatorial atom, and the distance given is an average of all the contributing distances.

The shortness of the Si-F distance and the observation that all the C-0 distances in the fluoro compound were shorter than the corresponding distances in the chloro compound suggested that the larger thermal motions of the former might be affecting our calculated distances significantly. A calculation of the bond distances of the Si-F bonds and the c-0 bonds was made using the riding model.¹⁹ The riding model is undoubtedly a very poor approximation for the thermal correction in the C-0 distance, but it is certainly better than the approximation of totally uncorrelated motion. The resulting "corrected" distances are: Si-F, 1.61 (1) *k;*

(18) B. Bak, J. Bruhn, and J. Brastrup-Andersen, *J. Chem. Phys.,* **21,** 752 (1953).

Figure 2.—Molecule viewed down the Co-Si axis showing approximate threefold symmetry.

 $C(E)$ -O(E), 1.17 (2) \hat{A} ; C(A)-O(A), 1.16 (2) \hat{A} . These carbonyl distances do not differ significantly from the corresponding uncorrected ones in the chloro compound. It seems likely that application of this correction to the bond distances in the chloro compound would bring them into even closer agreement.

The change in the Si-F distance on applying a thermal correction is not really surprising when the shape of the thermal ellipsoid for fluorine is considered (see Figure **2).** It is, however, a bit unexpected that the Si-F distance should, after thermal correction, be 0.02-0.06 A longer than previous electron diffraction and microwave determinations of the same distance in other silicon fluorides. Some lengthening of the crystal distance because of lattice vibrations is to be expected, but the magnitude of the observed change is surprising. Since this is the only fluorosilane derivative whose structure has been determined by X-ray diffraction, the authors are reluctant to draw any conclusions from these comparisons. Because of the large thermal motions of fluorine atoms, quoted bond distances in fluorine-containing molecules are very sensitive to thermal corrections, as the above discussion illustrates.

The environment of the Si in the fluoro compound deviates from tetrahedral symmetry in the same way as in its sister compound: the average F-Si-F angle of 103.7° is just slightly smaller than the 105.4° reported by Robinson and Ibers for the chloro derivative. The X-X nonbonded distance in both the chloro and fluoro compounds is approximately 90% of the expected van der Waals distance. The C-X distance from neighboring carbonyl groups exceeds the expected van der Waals distance in both compounds. On this basis it seems reasonable to attribute the $X-Si-X$ angle primarily to X-X nonbonding repulsions rather than to C-X repulsions from the carbonyl groups.

The coordination sphere about the cobalt atom is trigonal bipyramidal, and the bond angles reported here for cobalt do not differ significantly from those reported for the chloro derivative. In both compounds the equatorial carbonyl groups are bent out of the basal plane in the direction of the silyl group. The equatorial carbonyls and the fluorines are staggered, as can be seen in Figure 1.

The Si-Co bond distance in the fluoro derivative is

⁽¹⁴⁾ J. Sheridan and **W.** Gordy, *J. Chem. Phys.,* **19,** 965 (1951).

⁽¹⁵⁾ R. L. Livingston and L. 0. Brockway, *J. Am. Chem. Soc.,* **66,** ⁹⁴ (1944). (16) G. A. Heath, L. F. Thomas, and J. Sheridan, *Trans. Faraday Soc.*, 50,

^{779 (1954).} (17) L. 0. Brockway and F. G. Wall, *J. Am. Chem. Soc.,* **56, 2373 (1934).**

⁽¹⁹⁾ W. R. Busing and H. A. Levy, *Acta Cryst.,* **17,** 142 (1964).

shorter than the corresponding distance in the chloro derivative, supporting the hypothesis of a $(d \rightarrow d) \pi$ bond between these atoms. The other distances which Robinson and Ibers suggested' might provide additional evidence for such a bond were not significantly different in the two compounds.

Acknowledgments.-The authors wish to thank Dr. A. G. McDiarmid for calling their attention to this problem and Dr. A. P. Hagen for providing the sample of $F_3SiCo(CO)_4$. Special thanks are also due to Mr. R. J. Dellaca for his contribution to the computer programs used in this determination.

CONTRIBUTION FROM THE DEPARTMENT OF CHEMISTRY. XORTHWESTERN UNIVERSITY, EVANSTOS, ILLIXOIS 60201

The Crystal Structure of Solvated Hydridochloro(**trichlorosilyl)bis(triphenylphosphine)rhodium,** $RhHCl(SiCl₃)(P(C₆H₅)₃)₂·xSiHCl₃$

BY KENNETH W. MUIR AND JAMES A. IBERS

Received July 25, 1969

The crystal structure of solvated hydridochloro(trichlorosilyl)bis(triphenylphosphine)rhodium, $RhHCl(SiCl_3)(P(C_6H_5)_3)_2$. x SiHCl₃, has been determined by X-ray diffraction methods. The compound crystallizes in the space group C_1 ¹-P \bar{I} of the triclinic system. There are two molecules of RhHCl(SiCl₃)(P(C₆H₅)₃)₂ in a unit cell of dimensions $a = 11.727$ (5) Å, $b =$ 12.952 (6) Å, $c = 13.365$ (5) Å, $\alpha = 104.65$ (2)°, $\beta = 98.08$ (2)°, $\gamma = 94.43$ (2)°. The structure has been refined by leastsquares methods to a conventional *R* factor of 0.064 over 2485 counter-diffractometric data. It consists of discrete monomeric molecules of RhHCl(SiCl₃)(P(C₆H₅)₃)₂ and SiHCl₃. The latter are disordered over four different sites; the SiHCl₃: Rh ratio is 0.397 (7). The rhodium coordination polyhedron may be described as a highly distorted trigonal bipyramid, with $trans$ phosphines at the apices and H, C1, and SiCl₃ in the trigonal plane. Alternatively, the coordination about the formally d6 Rh(II1) ion is distorted octahedral if one chooses to include at the sixth coordination site the contact of 2.79 **A** with an *ortho-*hydrogen atom on a phenyl ring of a triphenylphosphine group. The short Rh-Si distance of 2.203 (4) Å is consistent with back-donation of electrons from the metal to the silyl group.

Introduction

The nature of metal-silicon bonding in transition metal-silyl complexes is at present a subject of debate.^{1,2} Structural details have been published only for the cobalt complexes $Co(SiR_3)(CO)_4$ (R = F,³ Cl,⁴) H^5) and for $Mn(Si(CH_3)_3)(CO)_5$ ⁶ It is our contention that a fruitful discussion of such problems as the relative importance of $d_{\pi}-d_{\pi}$ back-bonding and electronegativity differences in stabilizing metal-silicon bonds and whether the metal-silicon bond may appropriately be considered as a metal-metal bond will only be possible if adequate structural data are at hand on a sufficient number of representative metal-silyl complexes.

Accordingly, we have determined the crystal structure of the formally d^6 complex hydridochloro(tri**chlorosilyl)bis(triphenylphosphine)rhodium(III),** Rh- $HC1(SiCl₃)(P(C₆H₅)₃)₂$. This compound was chosen because we believed that back-donation to silicon would be favored by the presence of a second- as opposed to a first-row transition metal and by the absence of strongly π -bonding ligands such as carbonyl. In addition, this compound contains five-coordinate rhodium(II1). Five-coordination is much less common in d^s systems than it is in d^0 , d^8 , or d^{10} systems;⁷ the only d^6 complexes for which structural data arc available are the ruthenium(II) complexes $RuXC1(P(C_6H_5)_3)_3$ (X = $Cl₁⁸$ H⁹) and Rh(CH₃)I₂(P(C₆H₅)₃)₂.¹⁰ Further motives for our interest in this molecule were the presence of a metal-hydrogen bond and the relationship between the structure of the molecule and its postulated role as an intermediate in the catalytic hydrosilation of olefins.

The compound RhHCl(SiCl₃)($P(C_6H_5)_3$)₂ has been prepared independently by two groups. Haszeldine, Parish, and Parry'l obtained an unsolvated complex. While this work was underway, de Charentenay, *Os*born, and Wilkinson¹² reported a slightly different preparation which yields solvated complexes; these authors suggested that the complexes containing free

(11) R. N. Haszeldine, R. V. Parish, and D. J. Parry, *J. Ovganomefal. Chem.* (Amsterdam), **9, 13** (1967); *J. Chem.* Soc., *A,* 683 (1969).

⁽¹⁾ F. G. A. Stone in **"New** Pathways in Inorganic Chemistry," E. A. V. Ebsworth, **A.** G. Maddox, and **A.** G. Sharpe, Ed., Cambridge University Press, Cambridge, England, 1968.

⁽²⁾ B. J. Aylett, *Aduan. Inorg. Chem. Radiochem.,* **11,** 249 (1968). **(3)** K. Emerson, P. R. Ireland, and W. **T.** Robinson, *Inovg. Chem.,* **9,** 436 (1970).

⁽⁴⁾ W. **T.** Robinson and J. **A.** Ibers, *ibid.,* **6,** 1208 (1967).

⁽⁵⁾ A. G. Robiette, G. M. Sheldrick, R. N. F. Simpson, B. J. Aylett, and J. **A.** Campbell, *J. Ovganometai Chem.* (Amsterdam), **14,** 279 (1968).

⁽⁶⁾ R. *S.* Hamilton and E. R. Corey, Abstracts, 156th National Meeting **of** the American Chemical Society, Atlantic City, N. J., Sept 1968, No. INOR 025.

⁽⁷⁾ E. L. Muetterties and R. A. Schunn, *Quart Rev.* (London), 20, 245

 (1966) .

⁽⁸⁾ *S.* J. La Placa and J. **A.** Ibers, *Inorg. Chem.,* **4,** 778 (1965).

⁽⁹⁾ A. C. Skapski and P. G. H. Troughton, *Chem. Commuu.,* 1230 (1968).

⁽¹⁰⁾ P. G. H. Troughton and A. C. Skapski, *ibid.,* 575 (1968).

⁽¹²⁾ F. de Charentenay, J. A. Osborn, and G. Wilkinson, *ibid., A,* 787 (1968).